μA741

HIGH PERFORMANCE OPERATIONAL AMPLIFIER

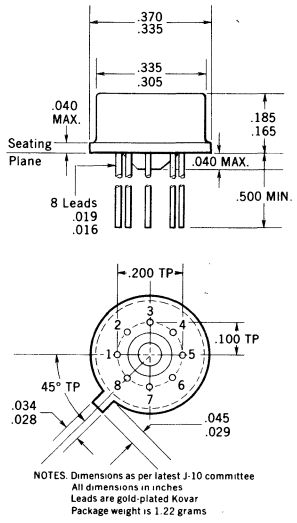
FAIRCHILD LINEAR INTEGRATED CIRCUITS

- **NO FREQUENCY COMPENSATION REQUIRED**
- **SHORT-CIRCUIT PROTECTION**
- **OFFSET VOLTAGE NULL CAPABILITY**
- **LARGE COMMON-MODE AND DIFFERENTIAL VOLTAGE RANGES**
- **LOW POWER CONSUMPTION**
- **NO LATCH UP**

GENERAL DESCRIPTION — The μA741 is a high performance monolithic operational amplifier constructed on a single silicon chip, using the Fairchild Planar* epitaxial process. It is intended for a wide range of analog applications. High common mode voltage range and absence of "latch-up" tendencies make the μA741 ideal for use as a voltage follower. The high gain and wide range of operating voltages provide superior performance in integrator, summing amplifier, and general feedback applications. The μA741 is short-circuit protected, has the same pin configuration as the popular μA709 operational amplifier, but requires no external components for frequency compensation. The internal 6dB/octave roll-off insures stability in closed loop applications.

PHYSICAL DIMENSIONS

in accordance with
JEDEC (TO-99) outline



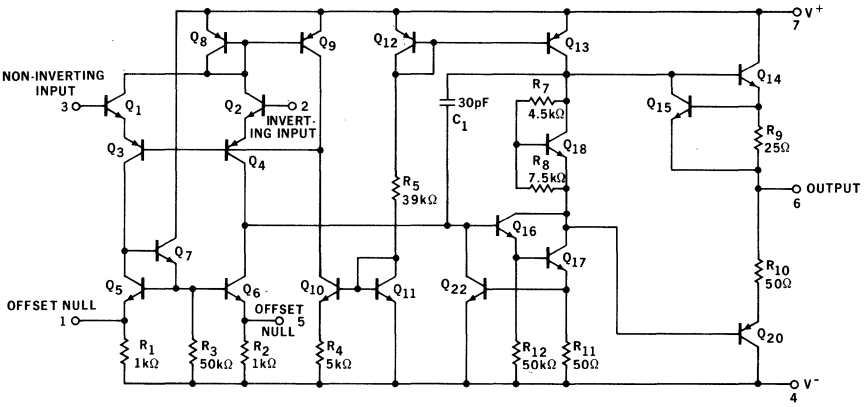
NOTES: Dimensions as per latest J-10 committee
All dimensions in inches
Leads are gold-plated Kovar
Package weight is 1.22 grams

ORDER PART NO. U5B7741312

ABSOLUTE MAXIMUM RATINGS

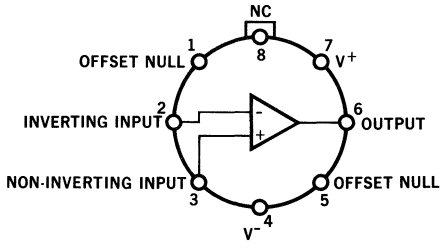
Supply Voltage	±22 V
Internal Power Dissipation (Note 1)	500 mW
Differential Input Voltage	±30 V
Input Voltage (Note 2)	±15 V
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−55°C to +125°C
Lead Temperature (Soldering, 60 sec)	300°C
Output Short-Circuit Duration (Note 3)	Indefinite

SCHEMATIC DIAGRAM



CONNECTION DIAGRAM

(TOP VIEW)



NOTE: PIN 4 CONNECTED TO CASE

NOTES:

(1) Rating applies for case temperatures to 125°C; derate linearly at 6.5 mW/°C for ambient temperatures above +75°C.
(2) For supply voltages less than ±15 V, the absolute maximum input voltage is equal to the supply voltage.
(3) Short circuit may be to ground or either supply. Rating applies to +125°C case temperature or +75°C ambient temperature.

*Planar is a patented Fairchild process.

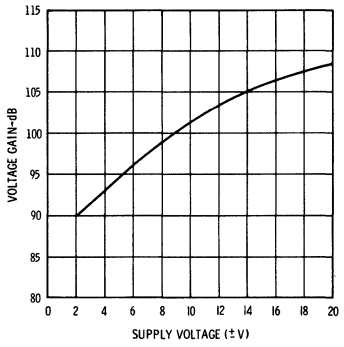
FAIRCHILD SEMICONDUCTOR
A DIVISION OF FAIRCHILD CAMERA AND INSTRUMENT CORPORATION

313 FAIRCHILD DRIVE, MOUNTAIN VIEW, CALIFORNIA, (415) 962-5011, TWX: 910-379-6435

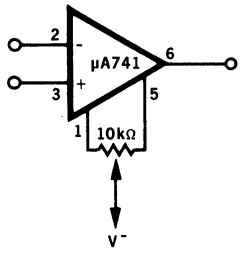
ELECTRICAL CHARACTERISTICS ($V_S = \pm 15$ V, $T_A = 25°C$ unless otherwise specified)

PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Offset Voltage	$R_S \leq 10$ kΩ		1.0	5.0	mV
Input Offset Current			30	200	nA
Input Bias Current			200	500	nA
Input Resistance		0.3	1.0		MΩ
Large-Signal Voltage Gain	$R_L \geq 2$kΩ, $V_{out} = \pm 10$ V	50,000	200,000		
Output Voltage Swing	$R_L \geq 10$ kΩ	±12	±14		V
	$R_L \geq 2$ kΩ	±10	±13		V
Input Voltage Range		±12	±13		V
Common Mode Rejection Ratio	$R_S \leq 10$ kΩ	70	90		dB
Supply Voltage Rejection Ratio	$R_S \leq 10$ kΩ		30	150	μV/V
Power Consumption			50	85	mW
Transient Response (unity gain)	$V_{in} = 20$ mV, $R_L = 2$ kΩ, $C_L \leq 100$ pF				
Risetime			0.3		μs
Overshoot			5.0		%
Slew Rate (unity gain)	$R_L \geq 2$ kΩ		0.5		V/μs
The following specifications apply for $-55°C \leq T_A \leq +125°C$:					
Input Offset Voltage	$R_S \leq 10$ kΩ			6.0	mV
Input Offset Current				500	nA
Input Bias Current				1.5	μA
Large-Signal Voltage Gain	$R_L \geq 2$kΩ, $V_{out} = \pm 10$ V	25,000			
Output Voltage Swing	$R_L \geq 2$ kΩ	±10			V

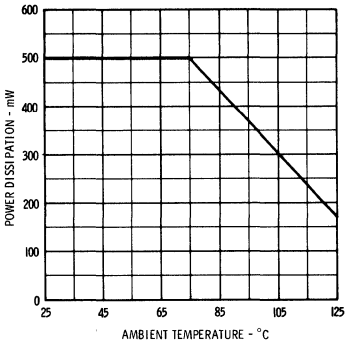
OPEN LOOP VOLTAGE GAIN



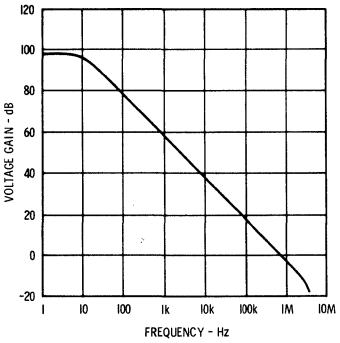
VOLTAGE OFFSET NULL CIRCUIT



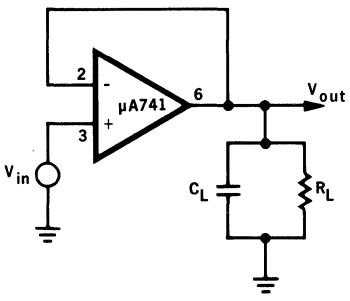
ABSOLUTE MAXIMUM POWER DISSIPATION



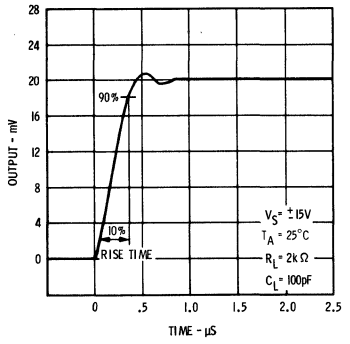
OPEN LOOP FREQUENCY RESPONSE



TRANSIENT RESPONSE TEST CIRCUIT



TRANSIENT RESPONSE



μA741C

HIGH PERFORMANCE OPERATIONAL AMPLIFIER

FAIRCHILD LINEAR INTEGRATED CIRCUITS

- **NO FREQUENCY COMPENSATION REQUIRED**
- **SHORT-CIRCUIT PROTECTION**
- **OFFSET VOLTAGE NULL CAPABILITY**
- **LARGE COMMON-MODE AND DIFFERENTIAL VOLTAGE RANGES**
- **LOW POWER CONSUMPTION**
- **NO LATCH UP**

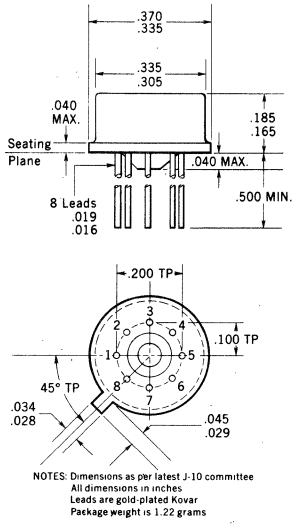
GENERAL DESCRIPTION — The μA741C is a high performance monolithic operational amplifier constructed on a single silicon chip, using the Fairchild Planar* epitaxial process. It is intended for a wide range of analog applications. High common mode voltage range and absence of "latch-up" tendencies make the μA741C ideal for use as a voltage follower. The high gain and wide range of operating voltages provide superior performance in integrator, summing amplifier, and general feedback applications. The μA741C is short-circuit protected, has the same pin configuration as the popular μA709 operational amplifier, but requires no external components for frequency compensation. The internal 6dB/octave roll-off insures stability in closed loop applications. For full temperature range operation (−55°C to +125°C) see μA741 data sheet.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	±18 V
Internal Power Dissipation	500 mW
Differential Input Voltage	±30 V
Input Voltage (Note 1)	±15 V
Storage Temperature Range TO-99	−65°C to +150°C
Dual-In-Line	−55°C to +125°C
Operating Temperature Range	0°C to +70°C
Lead Temperature (Soldering, 60 sec) TO-99	300°C
(Soldering, 10 sec) Dual-In-Line	260°C
Output Short-Circuit Duration (Note 2)	Indefinite

PHYSICAL DIMENSIONS

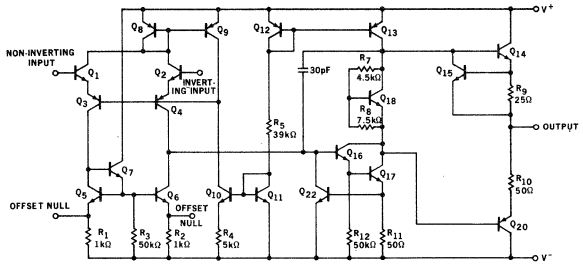
in accordance with JEDEC (TO-99) outline



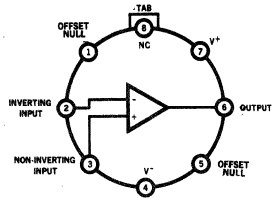
NOTES: Dimensions as per latest J-10 committee
All dimensions in inches
Leads are gold-plated Kovar
Package weight is 1.22 grams

ORDER PART NO. U5B7741393

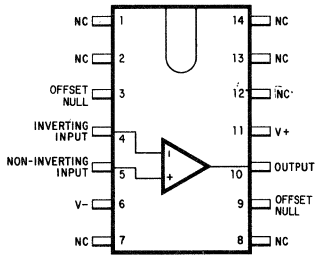
SCHEMATIC DIAGRAM



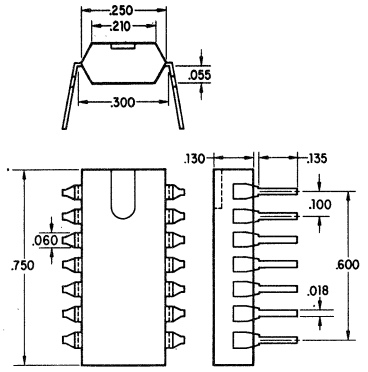
CONNECTION DIAGRAMS



NOTE: Pin 4 connected to case.



TYPICAL DUAL IN-LINE PACKAGE



NOTES: All dimensions in inches
Leads are intended for insertion in hole rows, .300 centers

ORDER PART NO. U6E7741393

*Planar is a patented Fairchild process.

NOTES:

(1) For supply voltages less than ±15 V, the absolute maximum input voltage is equal to the supply voltage.

(2) Short circuit may be to ground or either supply.

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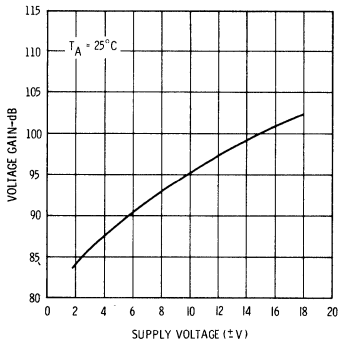
ELECTRICAL CHARACTERISTICS ($V_S = \pm 15$ V, $T_A = 25°C$ unless otherwise specified)

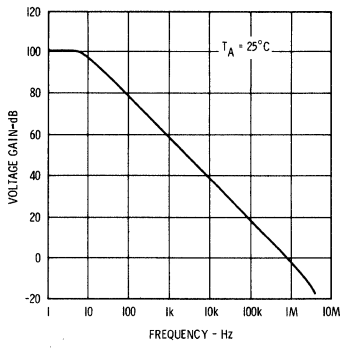
PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Offset Voltage	$R_S \leq 10$ kΩ		2.0	6.0	mV
Input Offset Current			30	200	nA
Input Bias Current			200	500	nA
Input Resistance		0.3	1.0		MΩ
Large-Signal Voltage Gain	$R_L \geq 2$ kΩ, $V_{out} = \pm 10$ V	20,000	100,000		
Output Voltage Swing	$R_L \geq 10$ kΩ	±12	±14		V
	$R_L \geq 2$ kΩ	±10	±13		V
Input Voltage Range		±12	±13		V
Common Mode Rejection Ratio	$R_S \leq 10$ kΩ	70	90		dB
Supply Voltage Rejection Ratio	$R_S \leq 10$ kΩ		30	150	μV/V
Power Consumption			50	85	mW
Transient Response (unity gain)	$V_{in} = 20$ mV, $R_L = 2$ kΩ				
	$C_L \leq 100$ pF				
Risetime			0.3		μs
Overshoot			5.0		%
Slew Rate (unity gain)	$R_L \geq 2$ kΩ		0.5		V/μs
The following specifications apply for $0°C \leq T_A \leq +70°C$:					
Input Offset Voltage	$R_S \leq 10$ kΩ			7.5	mV
Input Offset Current				300	nA
Input Bias Current				800	nA
Large-Signal Voltage Gain	$R_L \geq 2$ kΩ, $V_{out} = \pm 10$ V	15,000			
Output Voltage Swing	$R_L \geq 2$ kΩ	±10			V

TYPICAL PERFORMANCE CURVES

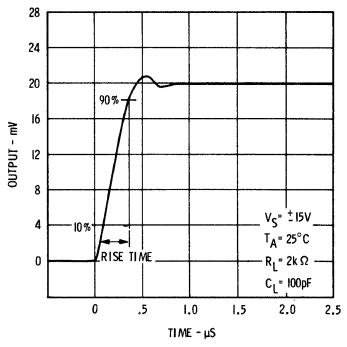
OPEN LOOP VOLTAGE GAIN



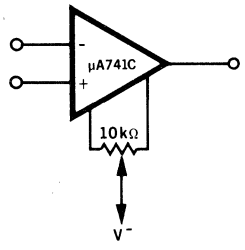
OPEN LOOP FREQUENCY RESPONSE



TRANSIENT RESPONSE



VOLTAGE OFFSET NULL CIRCUIT



TRANSIENT RESPONSE TEST CIRCUIT